

# HER801 THRU HER808

## GLASS PASSIVATED HIGH EFFICIENCY RECTIFIERS

Reverse Voltage – 50 to 1000 Volts

Forward Current – 8.0 Amperes

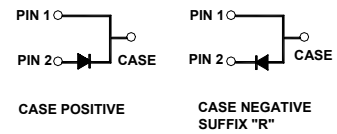
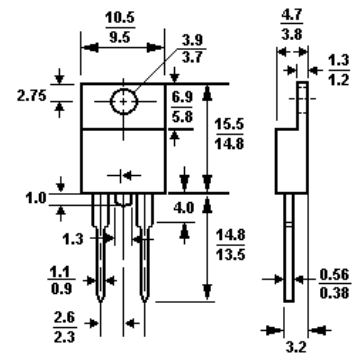
### Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0 utilizing Flame Retardant Epoxy Molding Compound
- Low power loss, high efficiency
- Low forward voltage, high current capability
- High surge capacity
- Ultra Fast recovery times, high voltage

### Mechanical Data

- **Case:** Molded plastic TO-220A
- **Mounting position:** Any
- **Terminals:** Leads solderable per MIL-STD-202, method 208 guaranteed
- **Polarity:** as marked

TO-220A



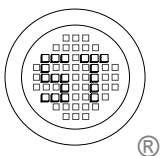
Dimensions in mm

### Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single-phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

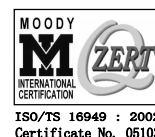
	Symbols	HER 801	HER 802	HER 803	HER 804	HER 805	HER 806	HER 807	HER 808	Units
Maximum recurrent peak reverse voltage	$V_{RRM}$	50	100	200	300	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	210	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	300	400	600	800	1000	V
Maximum average forward rectified current .375"(9.5mm) lead length at $T_C = 100^\circ C$	$I_{(AV)}$	8.0								A
Peak forward surge current , 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	$I_{FSM}$	150								A
Maximum forward voltage @ 8.0A	$V_F$	1.0		1.3		1.7				V
Maximum reverse current @ $T_A = 25^\circ C$ at rated DC blocking voltage @ $T_A = 125^\circ C$	$I_R$ $I_R$	10				500				uA uA
Typical junction capacitance (Note 1)	$C_J$	80				50				pF
Maximum reverse recovery time (Note 2)	$T_{rr}$	50				80				nS
Typical thermal resistance (Note3)	$R_{\theta JC}$	3.0								$^\circ C/W$
Operating temperature range	$T_J$	-55 to +150								$^\circ C$
Storage temperature range	$T_S$	-55 to +150								$^\circ C$

- Note: 1. Measured at 1 MHz and applied reverse voltage of 4.0 Volts D.C.  
2. Reverse recovery test conditions:  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{RR} = 0.25A$ .  
3. Thermal Resistance from junction to case mounted on heat sink.



**SEMTECH ELECTRONICS LTD.**

(Subsidiary of Semtech International Holdings Limited, a company listed on the Hong Kong Stock Exchange, Stock Code: 724)



ISO/TS 16949 : 2002  
Certificate No. 05103



ISO 14001  
Certificate No. 7116



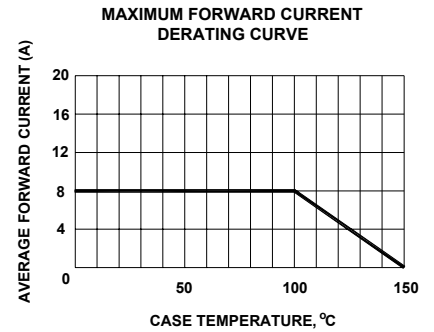
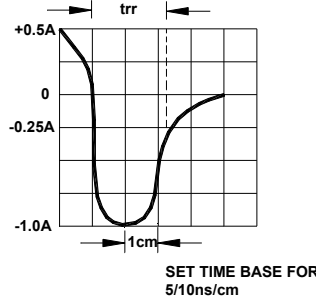
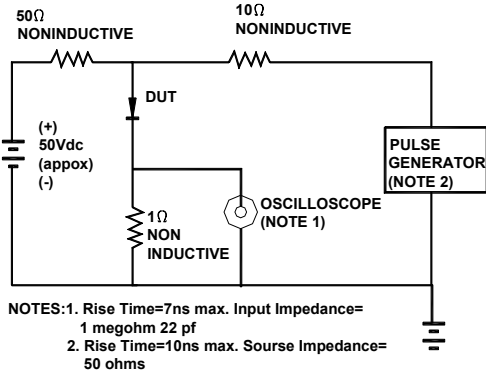
ISO 9001 : 2000  
Certificate No. 655-195-000-000

Dated : 24/09/2003

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## RATINGS AND CHARACTERISTIC CURVES

### REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



TYPICAL REVERSE CHARACTERISTICS

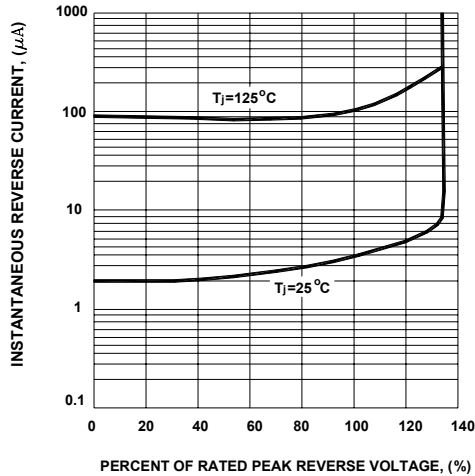


Fig. 4-TYPICAL FORWARD CHARACTERISTICS

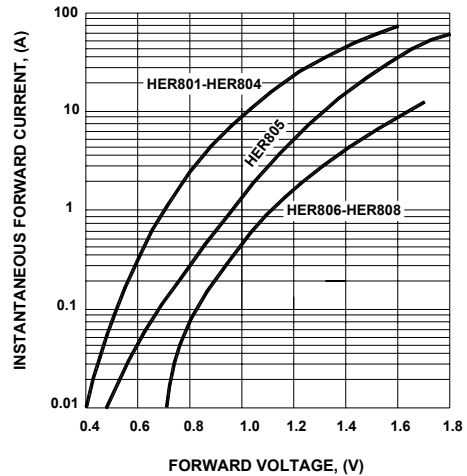


Fig. 5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

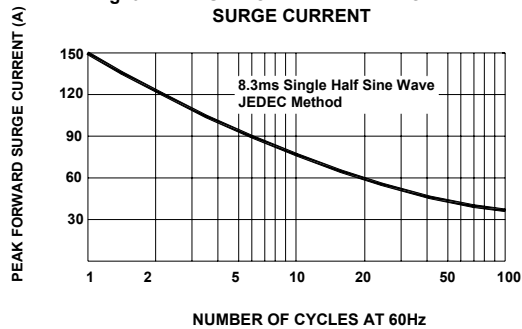
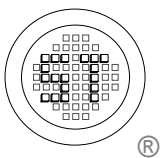
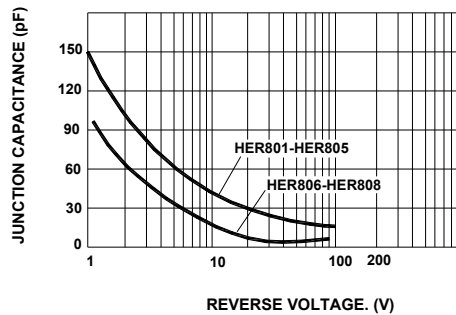
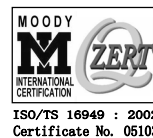


Fig. 6-TYPICAL JUNCTION CAPACITANCE



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